

Product Summary

V_{RRM} (V)	I_o (A)	$V_F(MAX)$ (V) @ +25°C	$I_R(MAX)$ (mA) @ +25°C
10	6	0.48	0.3

Description and Applications

The SBRT6U10LP provides very low V_F and excellent reverse leakage stability at high temperatures. It is ideal for use as bypass diode and rectifier, freewheel diode or blocking diode in applications such as:

- Solar Panels
- Blocking Diode
- Bypass Diode
- Boost Diode
- Recirculating Diode

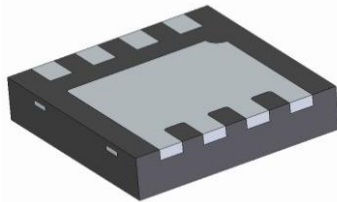
Features and Benefits

- Patented TrenchSBR technology provides superior avalanche capability versus Schottky diodes, ensuring more rugged and reliable end applications.
- Reduced ultra-low forward voltage drop (V_F); Better efficiency and cooler operation.
- Reduced high temperature reverse leakage; Increased reliability against thermal runaway failure in high temperature operation.
- **Totally Lead-Free Finish & RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

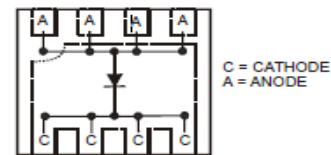
Mechanical Data

- Case: U-DFN3030-8
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (E3)
- Polarity: See Below
- Weight: 0.0199 grams (Approximate)

U-DFN3030-8



Bottom View



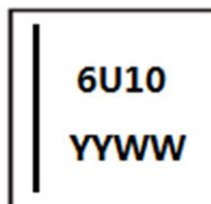
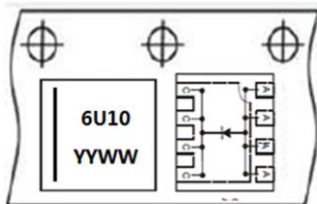
Top View
Internal Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
SBRT6U10LP-7	U-DFN3030-8	3,000/Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



6U10 = Product Type Marking Code
 YYWW = Date Code Marking
 YY= Last Digit of Year (ex: 14 = 2014)
 WW = Week Code (ex: 01-53)
 Bar=Cathode

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.
For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V _R RM	10	V
Working Peak Reverse Voltage	V _R WM		
DC Blocking Voltage	V _{RM}		
Average Rectified Output Current	I _O	6	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	55	A

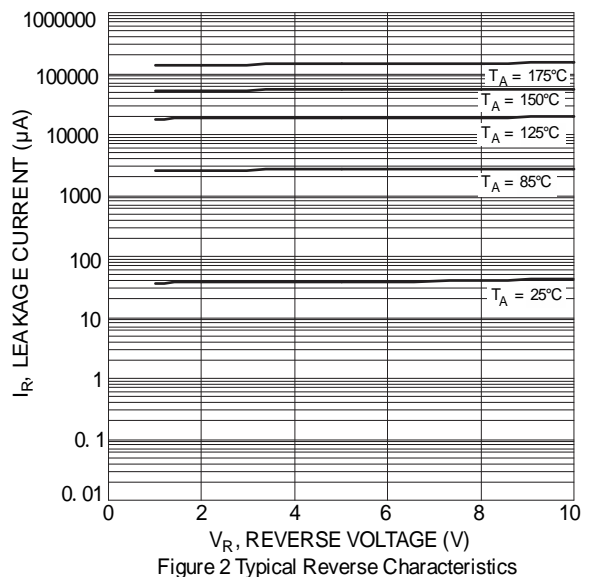
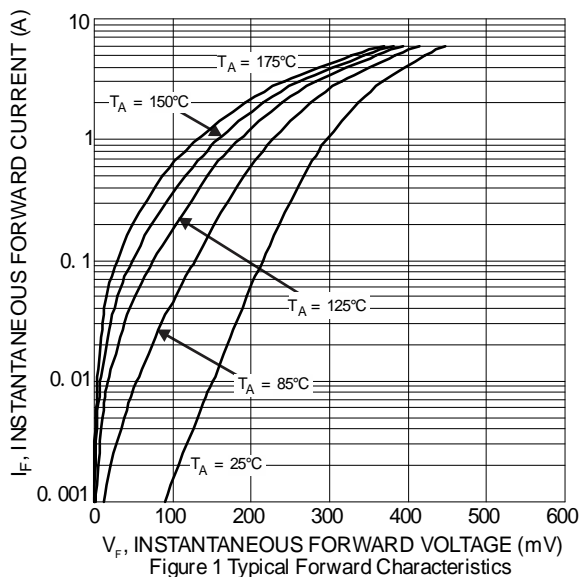
Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Case (Note 5)	R _θ JC	5.5	°C/W
Typical Thermal Resistance Junction to Ambient (Note 5)	R _θ JA	65	°C/W
Operating Temperature Range VR ≤ 80% VRRM VR ≤ 50% VRRM DC Forward Mode (Note 7)	T _J	-55 to +150 ≤175 ≤+200	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Forward Voltage Drop (Note 6)	V _F	—	—	0.48	V	I _F = 6A, T _J = +25°C
Leakage Current (Note 6)	I _R	—	—	300	μA	V _R = 10V, T _J = +25°C
		—	25	—	mA	V _R = 10V, T _J = +125°C

- Notes:
- Device mounted on FR-4 PCB pad layout 1-inch 2oz copper pad.
 - Short duration pulse test used to minimize self-heating effect.
 - Max junction temperature guaranteed for two hours.



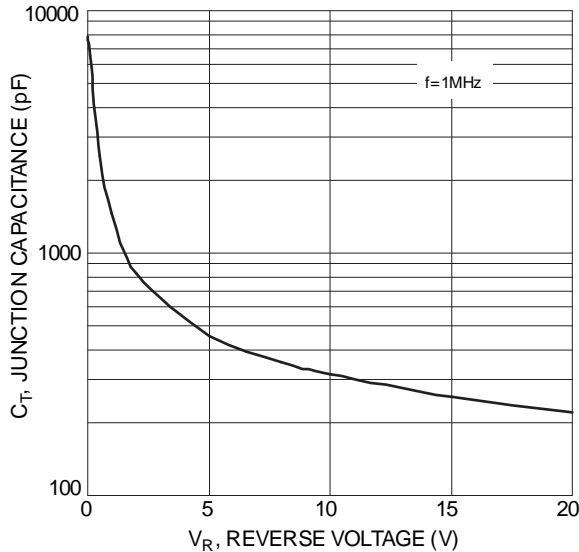


Figure 3 Typical Junction Capacitance

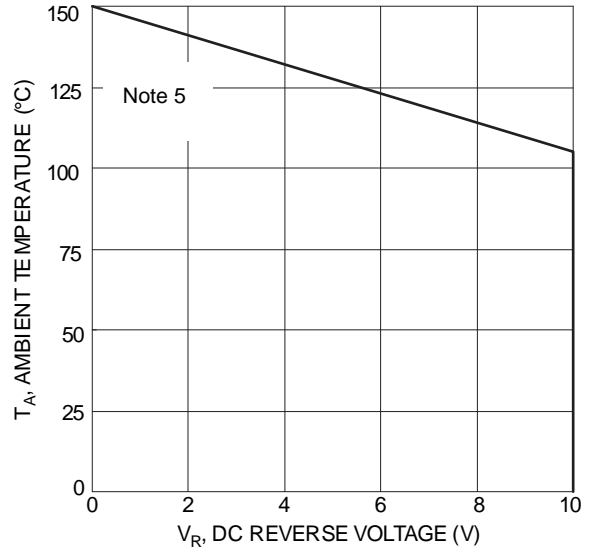


Figure 4 Operating Temperature Derating

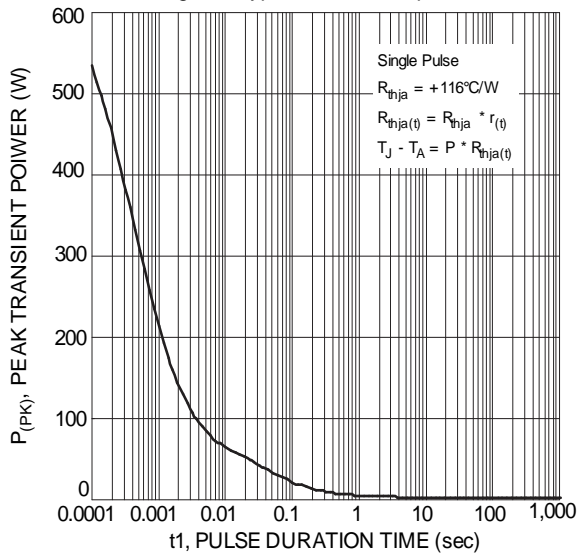


Figure 5 Single Pulse Maximum Power Dissipation

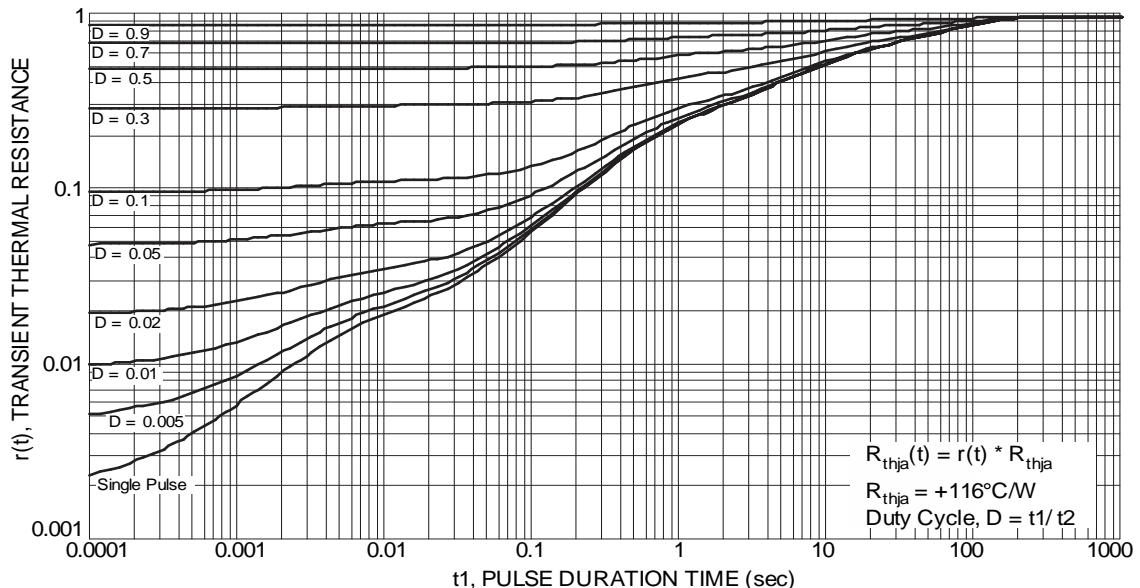
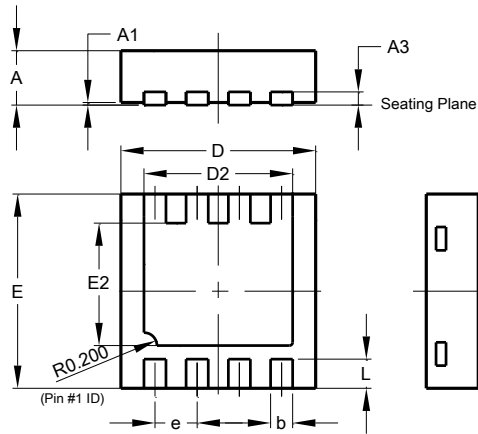


Figure 6 Transient Thermal Resistance

Package Outline Dimensions

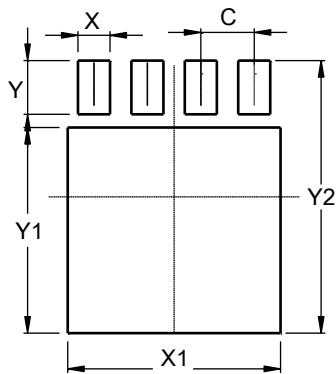
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



U-DFN3030-8			
Dim	Min	Max	Typ
A	0.57	0.63	0.60
A1	0	0.05	0.02
A3	—	—	0.15
b	0.29	0.39	0.34
D	2.90	3.10	3.00
D2	2.19	2.39	2.29
e	—	—	0.65
E	2.90	3.10	3.00
E2	1.64	1.84	1.74
L	0.30	0.60	0.45
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	0.650
X	0.390
X1	2.590
Y	0.650
Y1	2.490
Y3	3.300

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